properties of the 2D structures by measuring the specular reflection of light as a function of the wavelength of the incident field, observing a dip at 1100 nm, corresponding to the third-order Bragg reflection band. The researchers also demonstrated the potential of the 2D array of KTiOPO₄ rods to host an efficient nonlinear interaction by measurements of the diffracted light at the second-harmonic frequency of the incident wave.

This procedure enables control over the direction of growth relative to the orientation of the 2D structure. For any given application, it will then be possible to use the most appropriate combination of nonlinear or electro-optic coefficients of the material, something which is not always possible in bulk KTiOPO₄, given the limited material birefringence. Such newly developed photonic crystals, which should be easily integrated in siliconbased devices, may find applications in generating light more efficiently at higher frequencies, in the electro-optic modulation of light, and in obtaining backward parametric amplification and oscillation.

Submicrometer Technique Etches Curvilinear Silicon and Glass Patterns with HF-Saturated Hydrogel Stamps

Applications in micro-optics, microfluidics, and microelectronics call for micrometer-sized devices with curvilinear or multilevel surface topographies. Casting elastomers against rigid masters is a parallel process that can rapidly create such architectures, but the resulting polymeric devices possess low resistance to mechanical wear, are permeable to gases, and often swell when exposed to organic solvents. Durable inorganic substrates, with better mechanical and chemical properties, may be patterned by expensive techniques such as reactive ion etching, laser ablation, or micromachining, but the throughput rate of these serial processes is low. In the July 16 issue of Advanced Materials (p. 2004; DOI: 10.1002/adma.200600716), followed by a recent publication in *Chemistry of* Materials (p. 4722; DOI: 10.1021/ cm061468p), researchers at Northwestern University, led by B.A. Grzybowski, have presented a novel, inexpensive, directprinting technique that is suitable for rapid prototyping of multilevel reliefs in a variety of rigid substrates. The technique boasts a lateral resolution (in silicon) of several hundred nanometers, and it can pattern several square centimeters at a time.

Using soft lithographic techniques, Grzybowski and co-workers created a flexible hydrogel stamp by first patterning a reusable micropatterned master

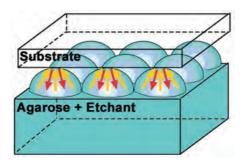
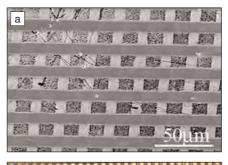
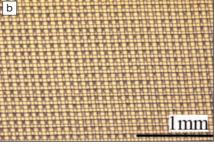


Figure 1. Schematic illustration of the experimental procedure for reaction-diffusion microetching.





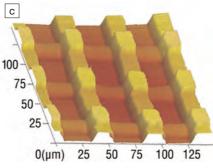


Figure 2. Three-dimensional (3D) architecture fabricated by sequential application of arrays of parallel lines along perpendicular directions. Pattern in GaAs: (a) scanning electron microscope image, (b) large-area optical micrograph, and (c) atomic force microscope image of a 3D structure showing trenches 0.7 µm and 0.4 µm deep. (Reprinted with permission from Chemistry of Materials 18 (20) (October 3, 2006) p. 4722; DOI: 10.1021/cm061468p; © 2006 American Chemical Society.)

with the desired topography, then casting high-gel-strength agarose against it. They "inked" the agarose stamp by soaking it for 4 h in a 0.6 M aqueous solution of hydrofluoric acid, with 0.1 vol% Triton X-100 surfactant.

The researchers laid the saturated stamp, feature side up, in light mineral oil, which confined the etchant to the raised features and reduced evaporation. Next, they placed the solid substrate to be patterned (e.g., a glass slide or a silicon wafer) directly upon the stamp, and ensured intimate contact by resting a small weight on top. Depending on the material system and the desired feature depth, the subsequent isotropic etching takes from several minutes to several days. The scientists then cleaned the etched surface using a piranha solution. The scheme is summarized in Figure 1.

The bulk agarose gel acts as a two-way "pump" that supplies fresh etchant and efficiently removes reaction products through diffusive transport. The etch rate is reaction-limited and is approximately constant. More concentrated acid solutions etch faster (which is helpful when making high-aspect-ratio features) but have detrimental effects on the stamp.

This easy-to-use, reliable method is reminiscent of woodcut printing, but on a submicrometer scale. The scientists have demonstrated the versatility of the technique by fabricating several difficult devices using their technique, including an array of convex/concave microfluses and a multilevel passive microfluidic mixer in glass.

"By exploiting other interfacial chemistries," Grzybowski said, "we have used the reaction-diffusion microetching process to pattern other materials, including zinc oxide and gallium arsenide." An example is shown in Figure 2.

RICH LOUIE

Nanocrystalline, Flexible Photoelectrochromic Films Display Quick Response Time

Changes in the optical properties of chromogenic materials occur by electric, thermal, or photo activation—for example, electrochromic "smart" windows that display switchable glazing. The change in color of photoelectrochromic (PEC) materials results from light absorption and application of an electric field. For example, a previously reported PEC device is based on an inorganic electrochromic film combined with a dye-sensitized semiconductor electrode. Recently, G. De Filpo and co-researchers at the Department of Chemistry, University of Calabria, Italy, developed a PEC film that uses a polymer-